

C2D10120D-Silicon Carbide Schottky Diode

ZERO RECOVERY® RECTIFIER

 $V_{RRM} = 1200 \text{ V}$

 $I_{E} = 10 A$

 $Q_c = 56 \text{ nC}$

Features

- 1200-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

PIN 1O O CASE

Package

TO-247-3

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives

Part Number	Package	Marking	
C2D10120D	TO-247-3	C2D10120	

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	1200	V		
V _{RSM}	Surge Peak Reverse Voltage	1200	V		
V _{DC}	DC Blocking Voltage	1200	V		
I _{F(AVG)}	Average Forward Current (Per Leg/Device)	7/14 10/20	А	T _c =149°C T _c =125°C	
$I_{\text{F(PEAK)}}$	Peak Forward Current (Per Leg/Device)	15/30	А	T _C =125°C, T _{REP} <1 mS, Duty=0.5	
I _{FRM}	Repetitive Peak Forward Surge Current	30*	А	T_c =25°C, t_p =10 ms, Half Sine Wave	
I _{FSM}	Non-Repetitive Peak Forward Surge Current	100*	А	$T_c=25$ °C, $t_p=10$ µs, Pulse	
P _{tot}	Power Dissipation	138* 46*	W	T _c =25°C T _c =125°C	
T _J , T _{stg}	Operating Junction and Storage Temperature	-55 to +175	°C		
	TO-247 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	

^{**} Per Device, * Per Leg



Electrical Characteristics (Per Leg)

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.6 2.6	1.8 3.0	V	$I_F = 5 \text{ A } T_J = 25^{\circ}\text{C}$ $I_F = 5 \text{ A } T_J = 175^{\circ}\text{C}$	
I_R	Reverse Current	50 100	200 1000	μΑ	$V_R = 1200 \text{ V } T_J = 25^{\circ}\text{C}$ $V_R = 1200 \text{ V } T_J = 175^{\circ}\text{C}$	
Q _c	Total Capacitive Charge	28		nC	$V_{R} = 1200 \text{ V, } I_{F} = 5 \text{ A}$ $di/dt = 500 \text{ A/}\mu\text{s}$ $T_{J} = 25^{\circ}\text{C}$	
С	Total Capacitance	455 45 33		pF	$V_R = 0 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 200 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 400 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$	

Note:

1. This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Тур.	Unit
$R_{_{ heta JC}}$	Thermal Resistance from Junction to Case	1.08** 0.54*	°C/W

^{**} Per Leg, * Both Legs

Typical Performance (Per Leg)

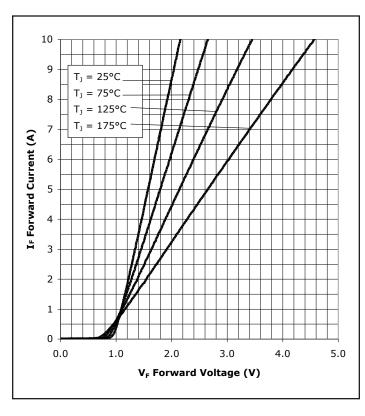


Figure 1. Forward Characteristics

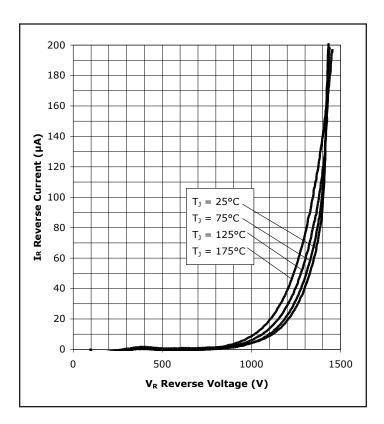
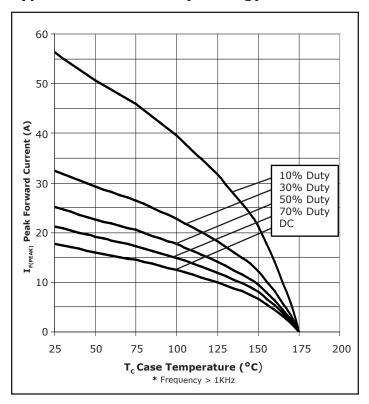


Figure 2. Reverse Characteristics



Typical Performance (Per Leg)



400 350 300 250 150 100 50 1 100 100 1000 V_R Reverse Voltage (V)

Figure 3. Current Derating

Figure 4. Capacitance vs. Reverse Voltage

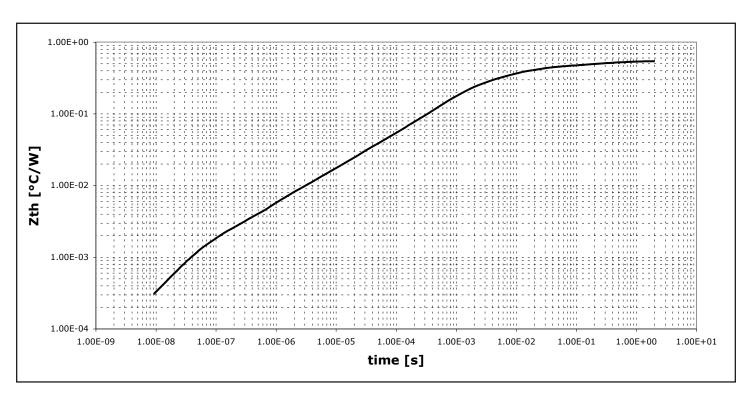
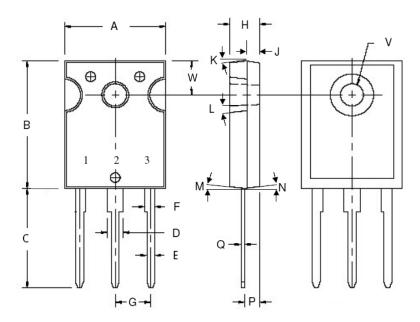


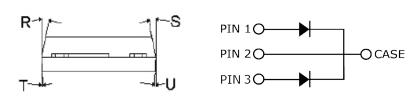
Figure 5. Transient Thermal Impedance



Package Dimensions

Package TO-247-3

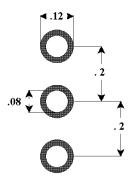




	Inc	hes	Millimeters		
POS	Min Max		Min	Max	
А	.605	.631	15.367	16.027	
В	.800	.830	20.320	21.082	
С	.620	.799	15.748	20.295	
D	.095	.126	2.413	3.200	
Е	.046	.052	1.168	1.321	
F	.060	.084	1.524	2.134	
G	.215	TYP	.215	TYP	
Н	.180	.203	4.572	5.156	
J	.078	.081	1.982	2.057	
K	6°	21°	6°	21°	
L	4°	6°	4°	6°	
М	2°	4°	2°	4°	
N	2°	4°	2°	4°	
Р	.090	.097	2.286	2.464	
Q	.020	.030	.508	.762	
R	9°	11°	9°	11°	
S	9°	11°	9°	11°	
Т	2°	8°	2°	8°	
U	2°	8°	2°	8°	
V	.138	.144	3.505	3.658	
W	.210	.220	5.334	5.588	



Recommended Solder Pad Layout



TO-247-3

Part Number	Package	Marking	
C2D10120D	TO-247-3	CSD10120	

"The levels of environmentally sensitive, persistent biologically toxic (PBT), persistent organic pollutants (POP), or otherwise restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2002/95/EC on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS), as amended through April 21, 2006."

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, air traffic control systems, or weapons systems.

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